CMOS Digital Integrated Circuits Silicon Monolithic

# 74HCT240D,74HCT244D

## 1. Functional Description

Octal Bus Buffer
 74HCT240D: INVERTED, 3-STATE OUTPUTS
 74HCT244D: NON-INVERTED, 3-STATE OUTPUTS

### 2. General

The 74HCT240D, and 74HCT244D are high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C<sup>2</sup>MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Their inputs are compatible with TTL, NMOS, and CMOS output voltage levels. The 74HCT240D is an inverting 3-state buffer having two active-low output enables. The 74HCT244D is non-inverting 3-state buffer the HCT244A has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

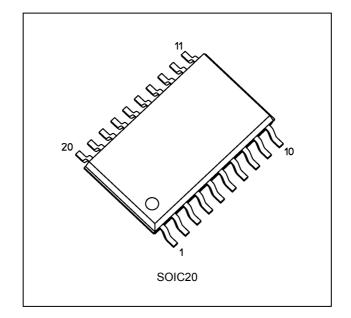
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

## 3. Features

- (1) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 1)
- (2) High speed:  $t_{pd}$  = 13 ns (typ.) at V<sub>CC</sub> = 5.5 V
- (3) Low power dissipation:  $I_{CC}$  = 4.0  $\mu$ A (max) at  $T_a$  = 25 °C
- (4) Compatible with TTL outputs:  $V_{IL} = 0.8 V(max)$ 
  - $V_{IH} = 2.0 V(min)$
- (5) Wide interfacing ability: LSTTL, NMOS, CMOS
- (6) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$

Note 1: Operating Range spec of T<sub>opr</sub> = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

#### 4. Packaging



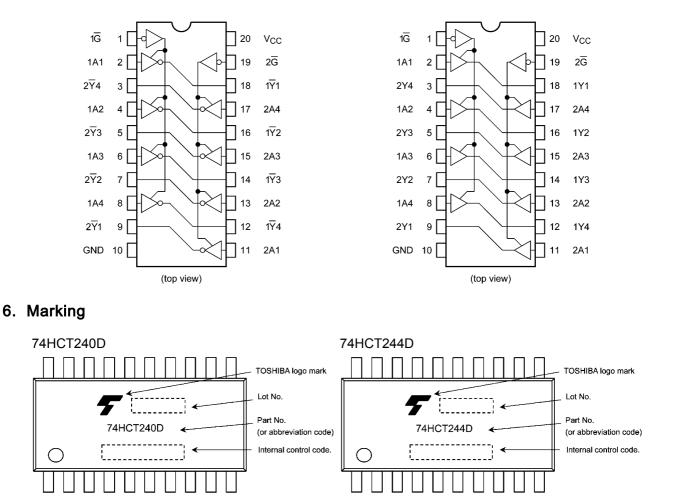
Start of commercial production 2020-07

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## 5. Pin Assignment

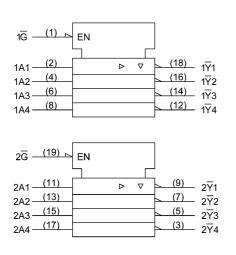
#### 74HCT240D



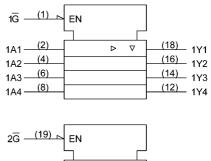


7. IEC Logic Symbol

74HCT240D



#### 74HCT244D





### 8. Truth Table

Input G	Input An	Output Yn	Output Yn
L	L	L	Н
L	Н	Н	L
Н	Х	Z	Z

X: Don't care

Z: High impedance

Yn: 74HCT244D

Yn: 74HCT240D

## 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Output voltage	V <sub>OUT</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		±20	mA
Output diode current	I <sub>ок</sub>		±20	mA
Output current	I <sub>OUT</sub>		±35	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±75	mA
Power dissipation	PD	(Note 1)	500	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P<sub>D</sub> derates linearly with -8 mW/°C above 85 °C

## 10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		4.5 to 5.5	V
Input voltage	V <sub>IN</sub>		0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>		0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	(Note 1)	-40 to 125	°C
Input rise and fall times	t <sub>r</sub> ,t <sub>f</sub>		0 to 500	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

## **11. Electrical Characteristics**

## 11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		4.5 to 5.5	2.0	_	_	V
Low-level input voltage	V <sub>IL</sub>	—		4.5 to 5.5	_	_	0.8	V
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -20 μA	4.5	4.4	4.5	—	V
			I <sub>OH</sub> = -6 mA	4.5	4.18	4.31	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	4.5	_	0.0	0.1	V
			I <sub>OL</sub> = 6 mA	4.5	_	0.17	0.26	
3-state output OFF-state leakage current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		5.5	_	—	±0.5	μΑ
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_		±0.1	μA
Quiescent supply	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	4.0	μA
current	I <sub>CCT</sub>	Per input: $V_{IN}$ = 0.5 V or 2.4 V Other input: $V_{CC}$ or GND		5.5	_	—	2.0	mA

## 11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		4.5 to 5.5	2.0	_	V
Low-level input voltage	VIL	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -20 μA	4.5	4.4	_	V
			I <sub>OH</sub> = -6 mA	4.5	4.13	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	4.5	_	0.1	V
			I <sub>OL</sub> = 6 mA	4.5	_	0.33	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$				±5.0	μA
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	40.0	μA
	I <sub>CCT</sub>	Per input: $V_{IN} = 0.5 V \text{ or } 2.4 V$ Other input: $V_{CC}$ or GND	V	5.5	—	2.9	mA

## 11.3. DC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Characteristics	Symbol	Test Condit	V <sub>CC</sub> (V)	Min	Max	Unit	
High-level input voltage	V <sub>IH</sub>	—		4.5 to 5.5	2.0	_	V
Low-level input voltage	VIL	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -20μA	4.5	4.4	_	V
			I <sub>OH</sub> = -6 mA	4.5	3.7	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20μA	4.5	_	0.1	V
			I <sub>OL</sub> = 6 mA	4.5	_	0.4	1
3-state output OFF-state leakage current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		5.5	_	±5.0	μA
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	V <sub>IN</sub> = V <sub>CC</sub> or GND		_	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	80.0	μA
	I <sub>ССТ</sub>	Per input: V <sub>IN</sub> = 0.5 V or 2.4 Other input: V <sub>CC</sub> or GND	4 V	5.5	—	2.9	mA

Note: Operating Range spec of T<sub>opr</sub> = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

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## 11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	C <sub>L</sub> (pF)	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
Output transition time		t <sub>TLH</sub> ,t <sub>THL</sub>		_	50	4.5	_	7	12	ns
						5.5	_	6	11	
Propagation delay time	74HCT240D	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	50	4.5	_	15	22	ns
						5.5	_	13	20	
					150	4.5	_	21	30	
						5.5	_	16	27	
Propagation delay time	74HCT244D	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	50	4.5	—	15	25	ns
						5.5	_	13	22	
					150	4.5	_	21	33	
						5.5	_	18	29	
3-state output enable time		t <sub>PZL</sub> ,t <sub>PZH</sub>		R <sub>L</sub> = 1 kΩ	50	4.5	_	17	30	ns
						5.5	_	14	27	
					150	4.5	_	23	38	
						5.5	_	20	34	
3-state output disable time		t <sub>PLZ</sub> ,t <sub>PHZ</sub>		R <sub>L</sub> = 1 kΩ	50	4.5	_	16	30	ns
						5.5	_	13	27	
Input capacitance		C <sub>IN</sub>		—			_	5	10	pF
Output capacitance		C <sub>OUT</sub>		_				10		pF
Power dissipation	74HCT240D	C <sub>PD</sub>	(Note 1)	—				33		pF
capacitance	74HCT244D	C <sub>PD</sub>		—			_	31	_	

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)}$  =  $C_{PD} \times V_{CC} \times f_{IN}$  +  $I_{CC}/8$  (per bit)

## 11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Part Number	Symbol	Test Condition	C <sub>L</sub> (pF)	V <sub>CC</sub> (V)	Min	Max	Unit
Output transition time		t <sub>TLH</sub> ,t <sub>THL</sub>	_	50	4.5	_	15	ns
					5.5	_	14	
Propagation delay time	74HCT240D	t <sub>PLH</sub> ,t <sub>PHL</sub>	—	50	4.5		28	ns
					5.5	_	25	
				150	4.5	_	38	
					5.5	_	34	
Propagation delay time	74HCT244D	t <sub>PLH</sub> ,t <sub>PHL</sub>	_	50	4.5	_	31	ns
					5.5	_	28	
				150	4.5	_	41	
					5.5	_	37	
3-state output enable time		t <sub>PZL</sub> ,t <sub>PZH</sub>	R <sub>L</sub> = 1 kΩ	50	4.5	_	38	ns
					5.5	_	34	
				150	4.5	_	48	
					5.5	_	43	
3-state output disable time		t <sub>PLZ</sub> ,t <sub>PHZ</sub>	R <sub>L</sub> = 1 kΩ	50	4.5	_	38	ns
					5.5	_	34	
Input capacitance		C <sub>IN</sub>	_		~		10	pF

#### 11.6. AC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C, Input: t<sub>r</sub> = t<sub>f</sub> = 6 ns)

Characteristics	Part Number	Symbol	Test Condition	C <sub>L</sub> (pF)	V <sub>CC</sub> (V)	Min	Max	Unit
Output transition time		t <sub>TLH</sub> ,t <sub>THL</sub>		50	4.5	_	17	ns
					5.5	_	16	
Propagation delay time	74HCT240D	t <sub>PLH</sub> ,t <sub>PHL</sub>	—	50	4.5	_	32	ns
					5.5	_	29	
				150	4.5	_	44	
					5.5	_	39	
Propagation delay time	74HCT244D	t <sub>PLH</sub> ,t <sub>PHL</sub>	_	50	4.5	_	35	ns
					5.5	_	32	
				150	4.5	_	47	
					5.5	_	43	
3-state output enable time		t <sub>PZL</sub> ,t <sub>PZH</sub>	R <sub>L</sub> = 1 kΩ	50	4.5	_	44	ns
					5.5	_	39	
				150	4.5	_	55	
					5.5	_	49	
3-state output disable time		t <sub>PLZ</sub> ,t <sub>PHZ</sub>	$R_L = 1 k\Omega$	50	4.5	_	44	ns
					5.5	_	39	1
Input capacitance		C <sub>IN</sub>	_			_	10	pF

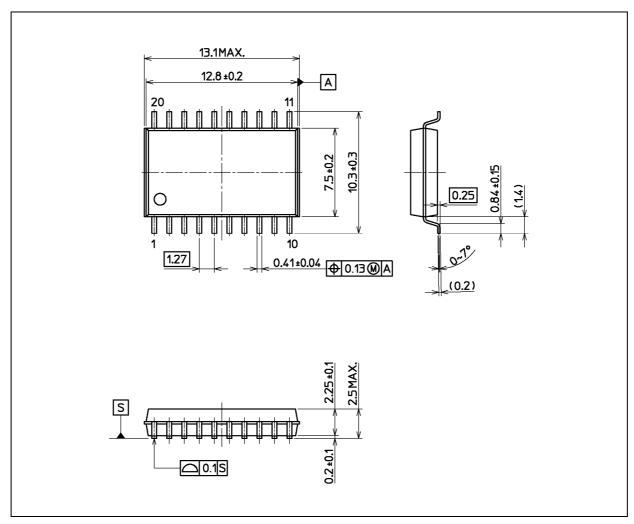
Note: Operating Range spec of T<sub>opr</sub> = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



## 74HCT240D,74HCT244D

### **Package Dimensions**

Unit: mm



Weight: 0.51 g (typ.)

Package Name(s)

Nickname: SOIC20

## TOSHIBA

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